
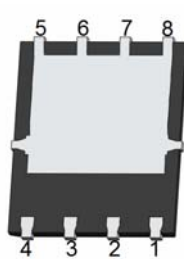
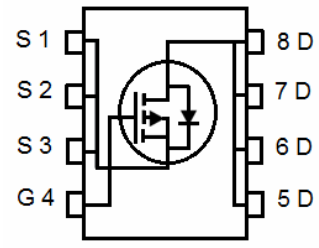


NCE P-Channel Super Trench Power MOSFET

<p>Description</p> <p>The NCEP40PT15G uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g. This device is ideal for high-frequency switching and synchronous rectification.</p> <p>Application</p> <ul style="list-style-type: none"> ● DC/DC Converter ● Ideal for high-frequency switching and synchronous rectification 	<p>General Features</p> <ul style="list-style-type: none"> ● $V_{DS} = -40V, I_D = -150A$ ● $R_{DS(ON)} = 2.8m\Omega$ (typical) @ $V_{GS} = -10V$ ● $R_{DS(ON)} = 3.8m\Omega$ (typical) @ $V_{GS} = -4.5V$ ● Excellent gate charge x $R_{DS(on)}$ product(FOM) ● Very low on-resistance $R_{DS(on)}$ ● 150 °C operating temperature ● Pb-free lead plating ● 100% UIS tested <p style="text-align: center; color: red; font-weight: bold;">100% UIS TESTED! 100% ΔV_{ds} TESTED!</p>
<p>DFN 5X6</p> <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="text-align: center;">  <p>Top View</p> </div> <div style="text-align: center;">  <p>Bottom View</p> </div> <div style="text-align: center;">  <p>Schematic Diagram</p> </div> </div>	

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP40PT15G	NCEP40PT15G	DFN5X6-8L	-	-	-

Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-40	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	-150	A
Drain Current-Continuous($T_C = 100^\circ C$)	$I_D(100^\circ C)$	-106	A
Pulsed Drain Current	I_{DM}	-600	A
Maximum Power Dissipation	P_D	150	W
Derating factor		1.2	W/ $^\circ C$
Single pulse avalanche energy ^(Note 5)	E_{AS}	1076	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^\circ C$

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{\theta JC}$	0.83	$^\circ C/W$
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Electrical Characteristics ($T_C=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-40		-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-40V, V_{GS}=0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.8	-1.2	-1.8	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-75A$	-	2.8	3.4	m Ω
		$V_{GS}=-4.5V, I_D=-75A$	-	3.8	4.6	m Ω
Forward Transconductance	g_{FS}	$V_{DS}=-5V, I_D=-75A$	-	30	-	S
Dynamic Characteristics (Note 4)						
Input Capacitance	C_{iss}	$V_{DS}=-20V, V_{GS}=0V,$ $F=1.0MHz$	-	8940	-	PF
Output Capacitance	C_{oss}		-	1900	-	PF
Reverse Transfer Capacitance	C_{rss}		-	45	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-20V, I_D=-75A$ $V_{GS}=-10V, R_G=1.6\Omega$	-	18	-	nS
Turn-on Rise Time	t_r		-	13	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	90	-	nS
Turn-Off Fall Time	t_f		-	15	-	nS
Total Gate Charge	Q_g	$V_{DS}=-20V, I_D=-75A,$ $V_{GS}=-10V$	-	104.4	-	nC
Gate-Source Charge	Q_{gs}		-	20.8	-	nC
Gate-Drain Charge	Q_{gd}		-	13.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	$V_{GS}=0V, I_S=-75A$	-		-1.2	V
Diode Forward Current (Note 2)	I_S		-	-	-150	A
Reverse Recovery Time	t_{rr}	$T_J = 25^\circ\text{C}, I_F = -75A$ $di/dt = 100A/\mu s$ (Note 3)	-		35	nS
Reverse Recovery Charge	Q_{rr}		-		85	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production
5. EAS condition : $T_J=25^\circ\text{C}, V_{DD}=-20V, V_G=-10V, L=0.5mH, R_g=25\Omega$

Typical Electrical and Thermal Characteristics

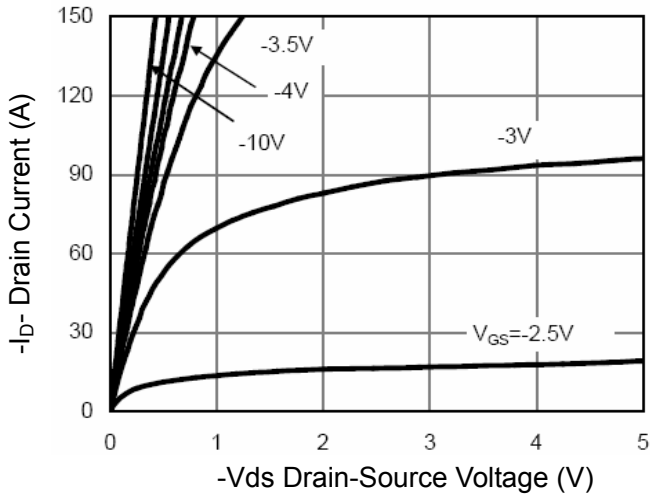


Figure 1 Output Characteristics

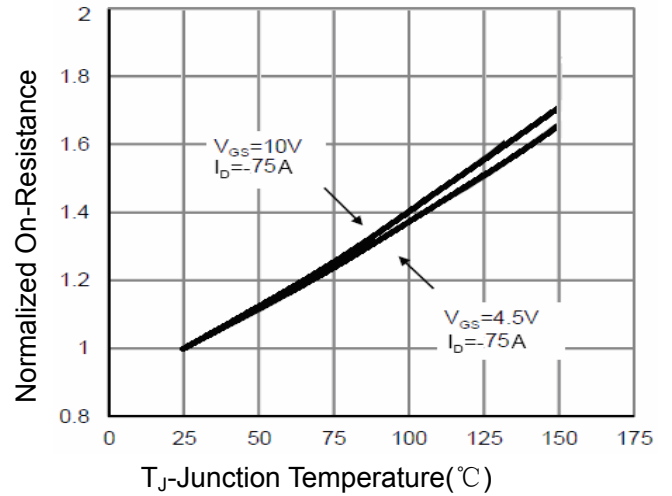


Figure 4 Rdson-Junction Temperature

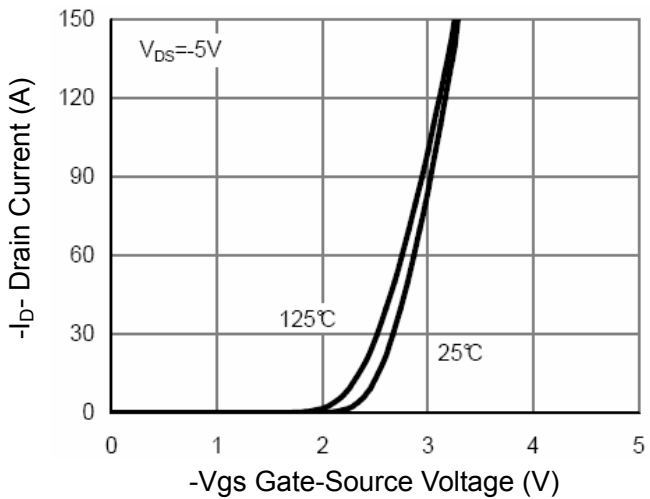


Figure 2 Transfer Characteristics

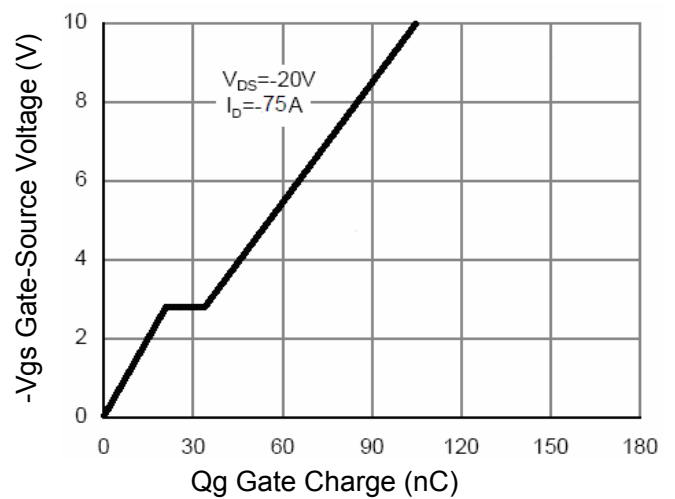


Figure 5 Gate Charge

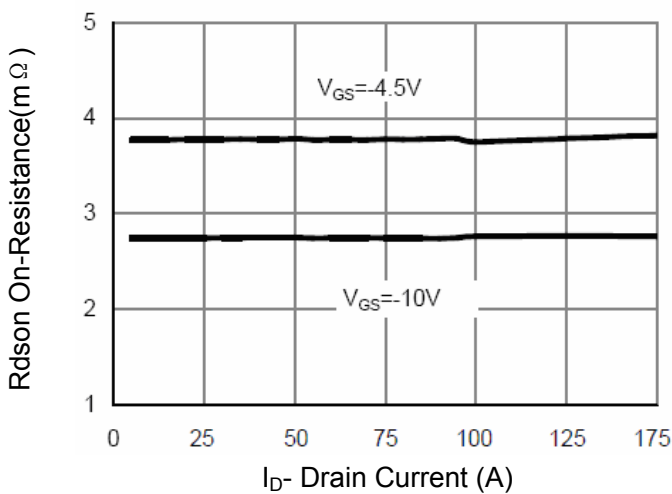


Figure 3 Rdson- Drain Current

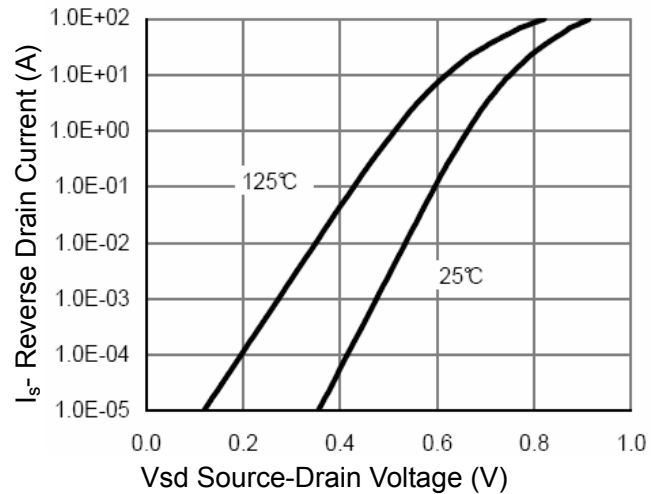


Figure 6 Source- Drain Diode Forward

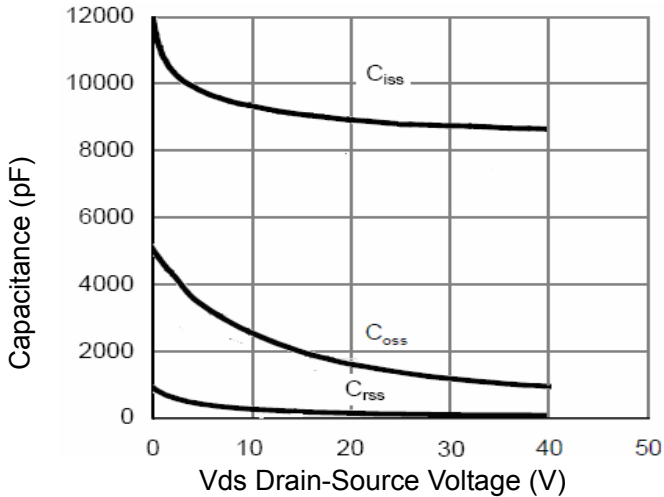


Figure 7 Capacitance vs Vds

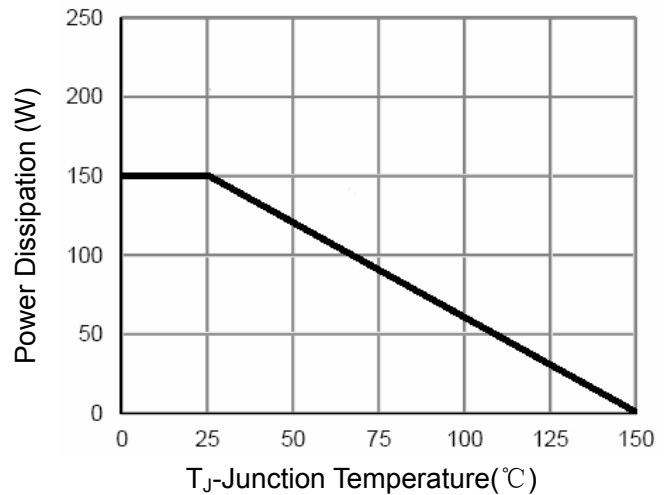


Figure 9 Power De-rating

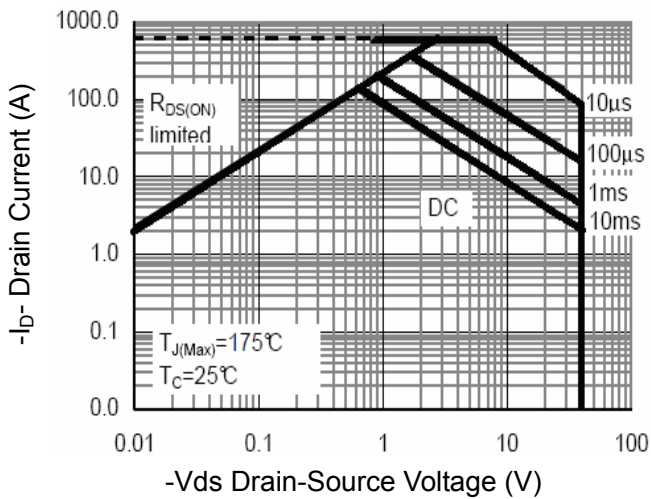


Figure 8 Safe Operation Area

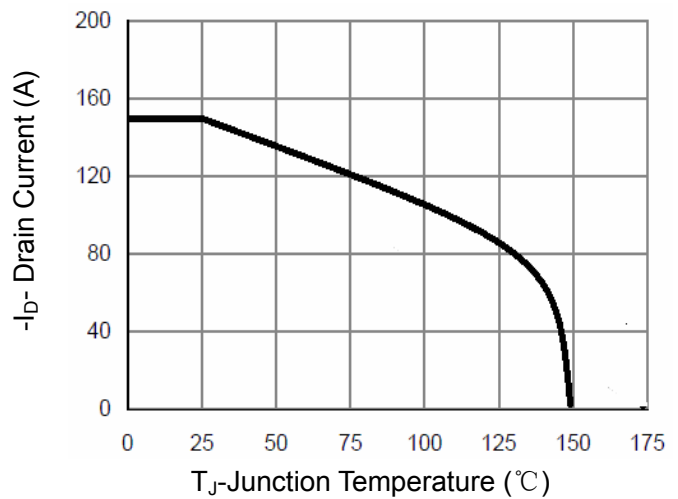


Figure 10 Current De-rating

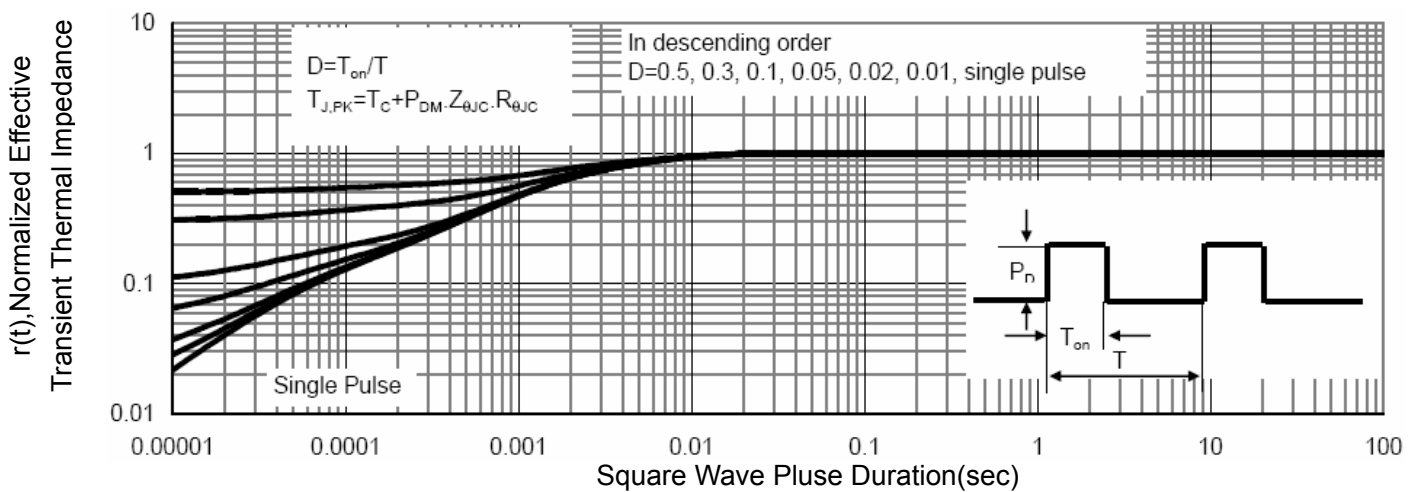
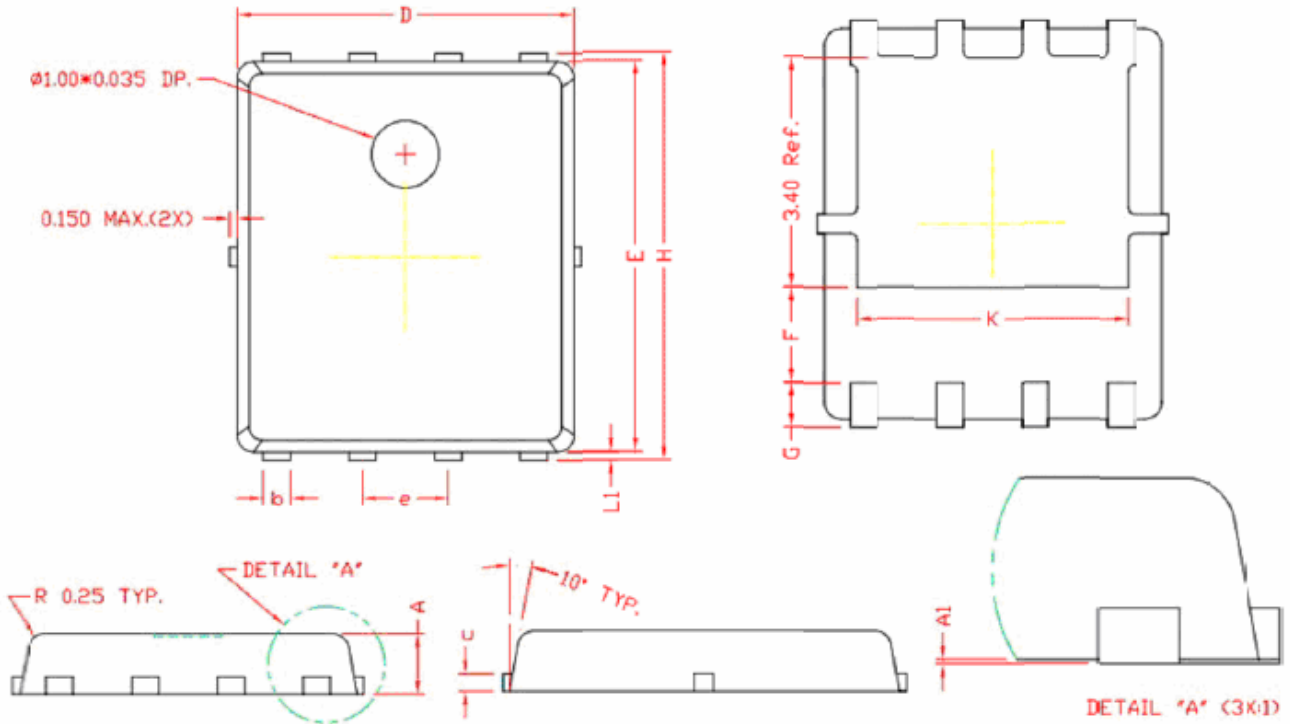


Figure 11 Normalized Maximum Transient Thermal Impedance

DFN5X6-8L Package Information



COMMON DIMENSIONS

(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NCM	MAX
A	0.80	0.90	1.00
A1	0.00	0.03	0.05
b	0.35	0.42	0.49
c	0.254 REF.		
D	4.90	5.00	5.10
F	1.40 REF.		
E	5.70	5.80	5.90
e	1.27 BSC.		
H	5.95	6.08	6.20
L1	0.10	0.14	0.18
G	0.60 REF.		
K	4.00 REF.		

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